

## Description

The ECM004 is a PCS power amplifier module at 3.5Volts Vcc with high efficiency. This device was developed using EiC's own InGaP Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process. It is optimized for PCS CDMA (digital) in the 1850 MHz to 1910 MHz band. It operates from a positive voltage (3 - 4Volts Vcc) and includes a power-down feature. The input and output are both matched to 50Ω. It is housed in a 6 X 6 mm Land Grid Array package.

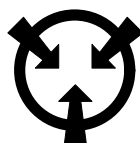
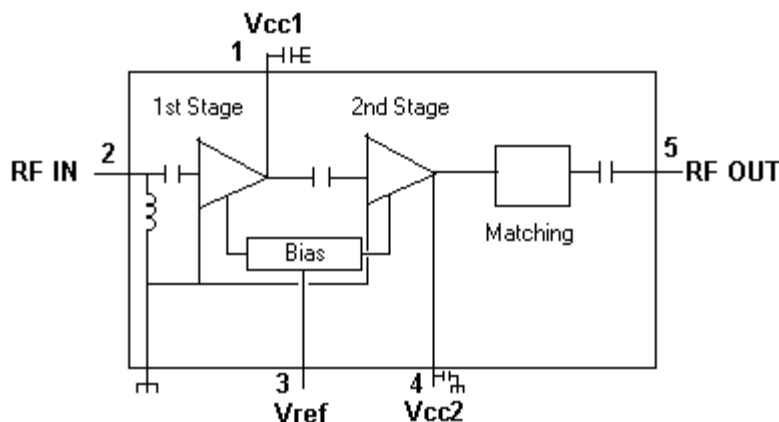
## Features

- U.S. PCS CDMA
- Single 3.5V Supply for 3-Cell Ni or Li-Ion Battery
- Power-down activated when Vref pin <1V
- 28.5 dBm CDMA Power
- 35% CDMA Efficiency
- Power-down Capability
- 80mA Typical Quiescent Current
- High Reliability InGaP Design

## Applications

- 3.5V U.S. PCS CDMA Handsets

## Functional Block Diagram



**CAUTION!**  
**SENSITIVE ELECTRONIC DEVICE**

## ELECTRICAL SPECIFICATIONS

The following tables list the electrical characteristics of the ECM004 Power Amplifier Module. Table 1 lists the electrical performance of the ECM004 for nominal operating conditions for the PCS band. Table 2 lists the absolute maximum ratings for continuous operation.

**Table 1 - Electrical Specifications**

Test Conditions:  $T_a = 25^\circ\text{C}$ ,  $V_{CC} = +3.5\text{V}$ ,  $V_{REF/PD}$  (reference / power-down voltage) = +2.9V,  $F = 1850$  to  $1910$  MHz

SYMBOL	PARAMETER	LIMITS			UNIT	TEST CONDITION
		MIN.	TYP.	MAX.		
F	Frequency	1850		1910	MHz	
G	Gain (CDMA Modulation) @ 28.5dBm	25	27		dB	
P	Output Power (CDMA)	28	28.5		dBm	NOTE 1
ACPR	Adjacent Channel Power Rejection @ 28.5dBm		-46	-44	dBc	NOTE 2
PAE	Power Added Efficiency (CDMA) @ 28.5 dBm	33	38		%	
	Output Stability		6:1		VSWR	NOTE 3
$I_{CQ}$	Quiescent Current (No RF)		80	100	mA	
$I_{Leak}$	Leakage Current (No RF)		10	20	uA	NOTE 4
$V_{CC}$	Supply Voltage		3.5		V	
IRL	Input Return Loss		10		dB	
NF	Noise Figure		5		dB	
$T_{ON/OFF}$	Power Down On/Off Time		<100		ns	
NOTE 1: Using Application Schematic. Tuned for CDMA.						
NOTE 2: @ 1250 KHz offset from band center.						
NOTE 3: No oscillation all phases						
NOTE 4: $V_{CC} = 3.5\text{V}$ , $V_{REF/PD} = 0\text{V}$ , No RF						

**Table 2 - Absolute Maximum Ratings**

Exceeding any of the absolute maximum ratings may cause permanent damage to the device. No damage assuming only one parameter is set at limit at a time with other parameters set at or below nominal value.

PARAMETER	RATING	UNIT	TEST CONDITION
Supply Voltage	7	Volts	$V_{REF/PD} = 2.9\text{V}$
Reference / Power-down Voltage( $V_{CC}=V_{REF/PD}$ )	4	Volts	$V_{CC} = 3.5\text{V}$
RF Power Input	+15	dBm	$V_{CC}$ , $V_{REF/PD} = 2.9\text{V}$
Ambient Operating Temperature	-40 to +110	$^\circ\text{C}$	
Storage Temperature	-65 to +140	$^\circ\text{C}$	



Figure 1

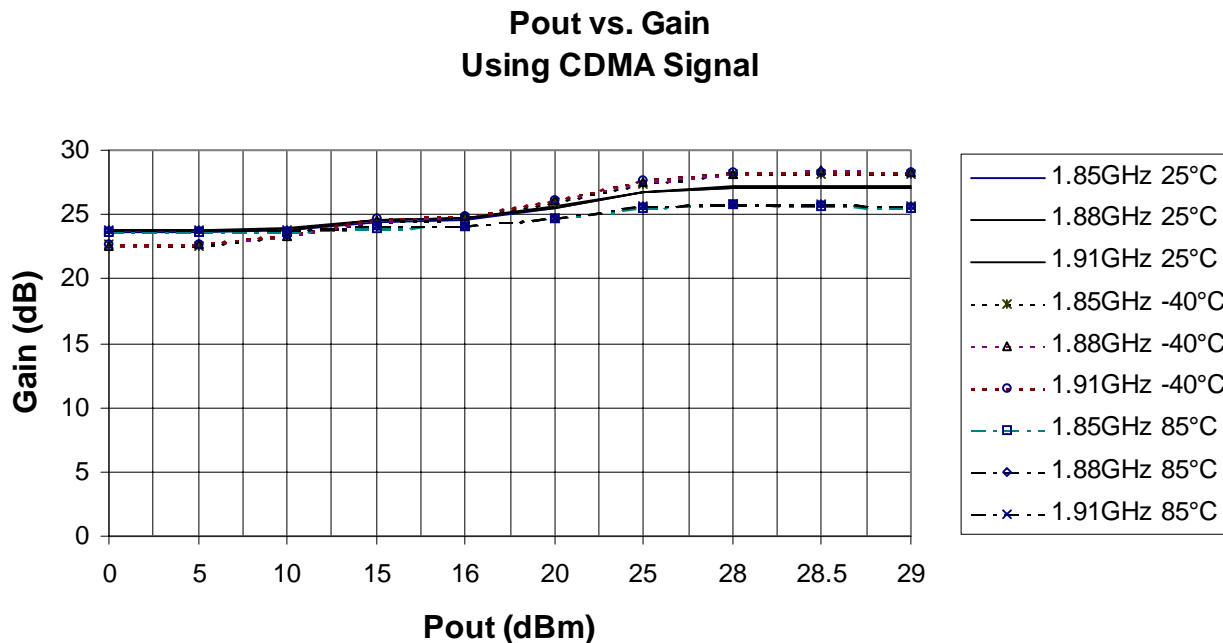


Figure 2

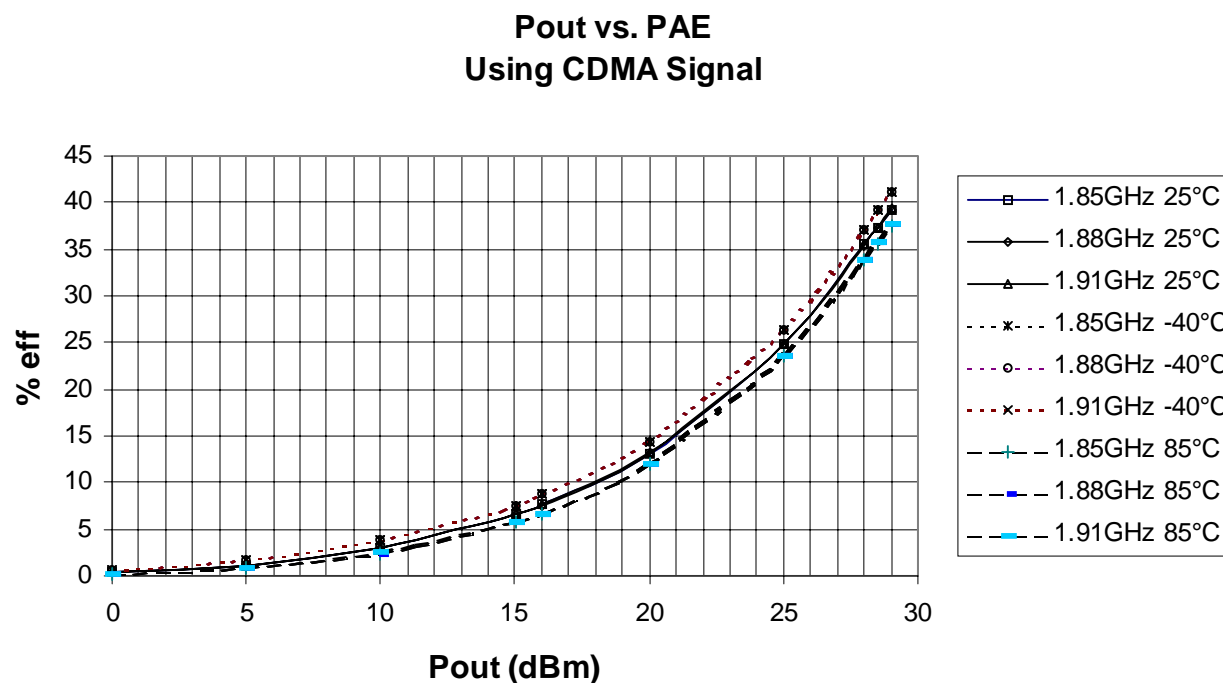


Figure 3

**Pout vs. ACPR1  
@ Pout 28.5dBm**

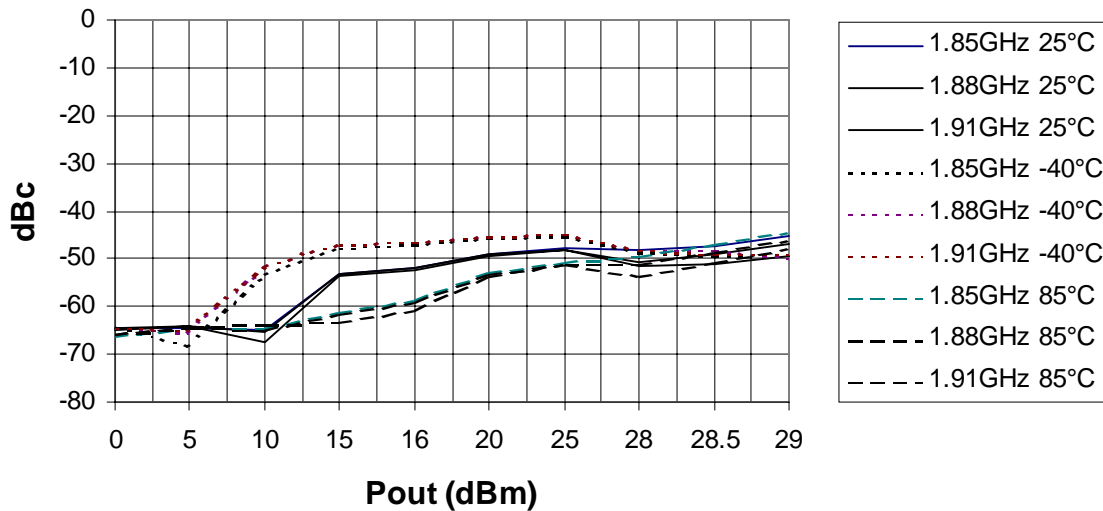


Figure 4

**IOP vs. Temperature vs. Frequency  
@ Pout 28.5dBm**

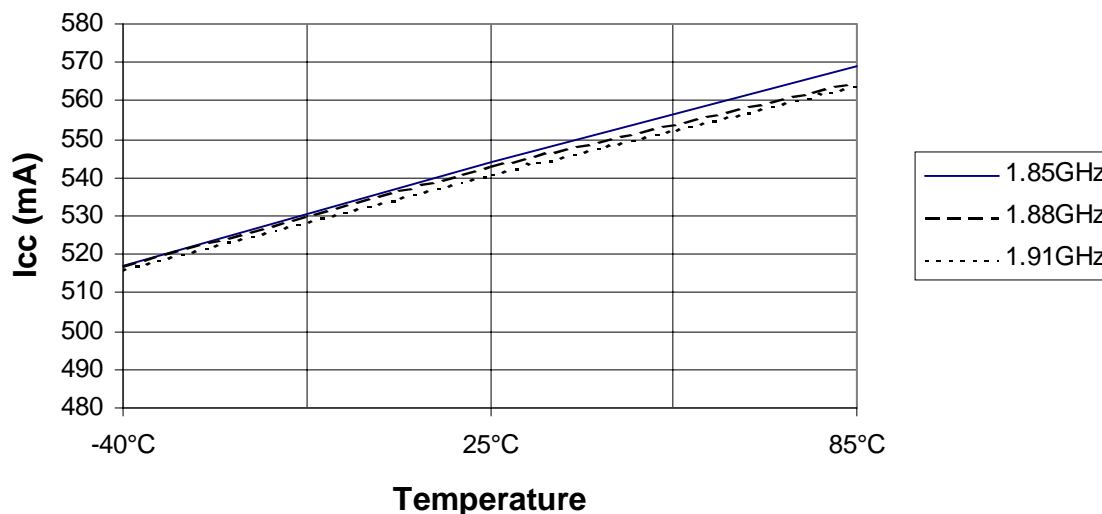


Figure 5

**GCDMA vs. Temperature vs. Frequency  
@ Pout 28.5dBm**

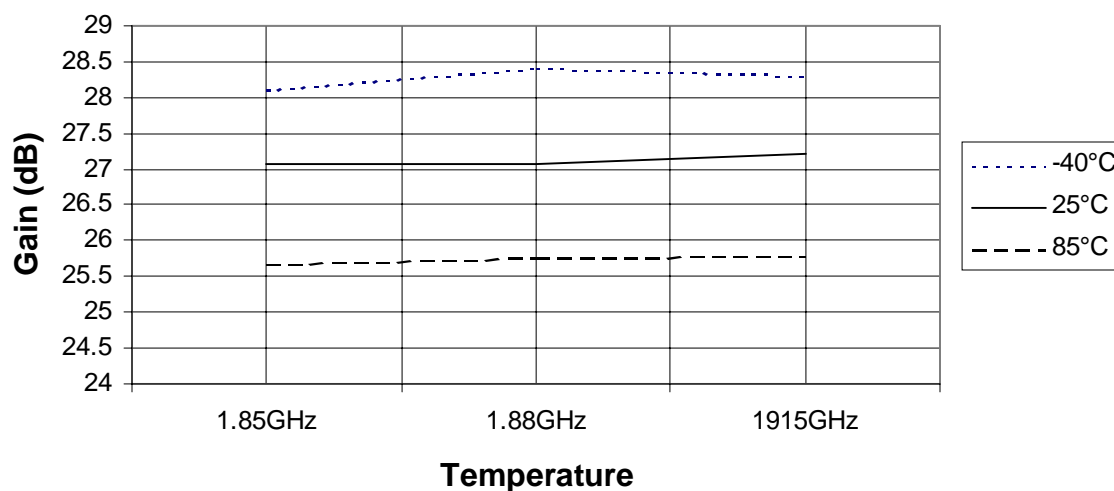


Figure 6

**ACPR1 vs. Temperature vs. Frequency  
@ Pout 28.5dBm**

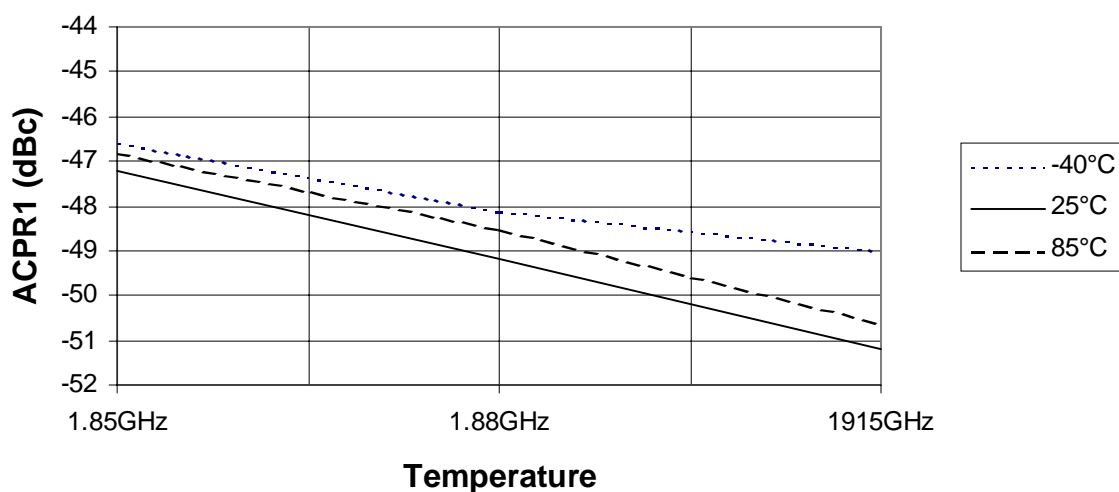


Figure 7

**GCDMA vs. Temperature vs. Frequency  
@ Pout 28.0dBm**

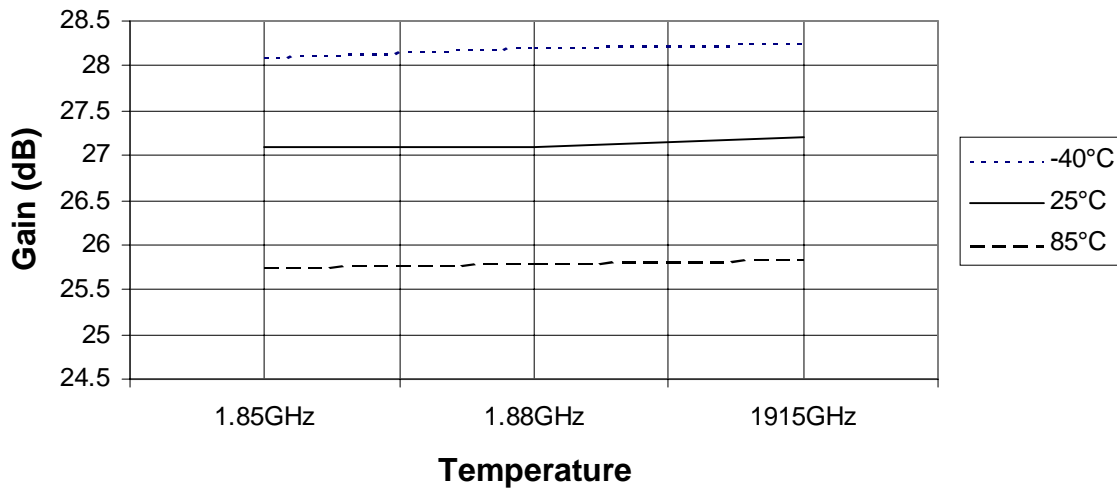


Figure 8

**IOP vs. Temperature vs. Frequency  
@ Pout 28.0dBm**

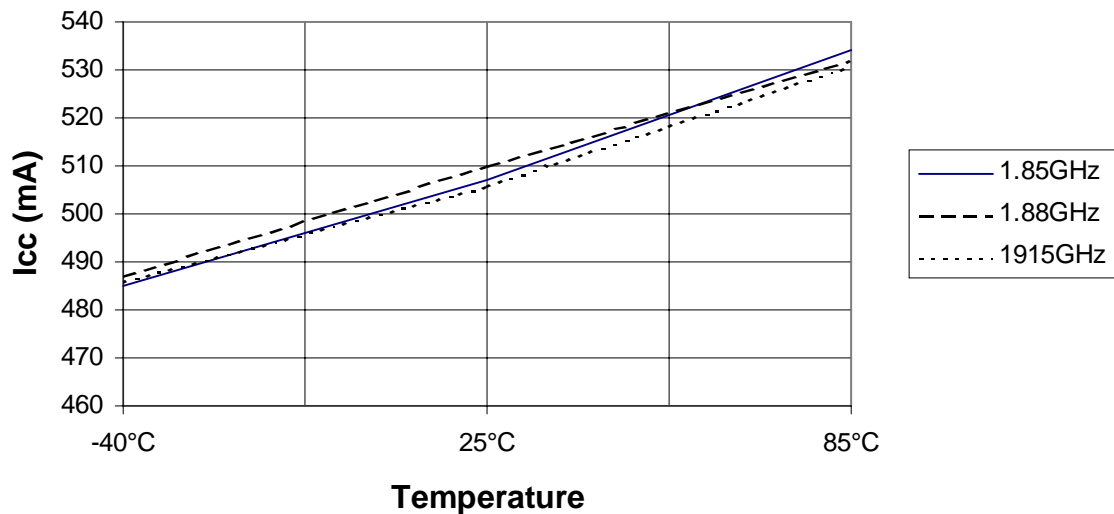
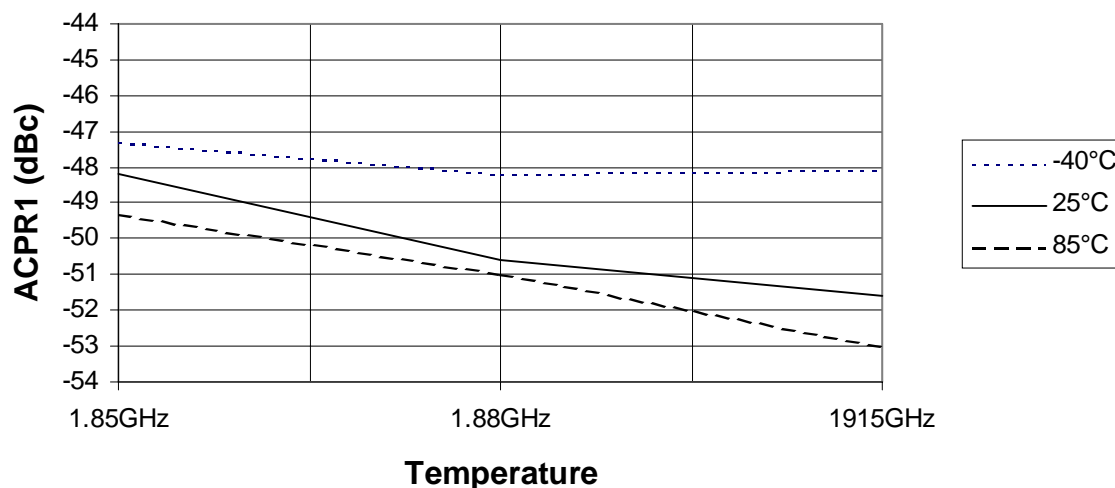


Figure 9

**ACPR1 vs. Temperature vs. Frequency  
@ Pout 28.0dBm**

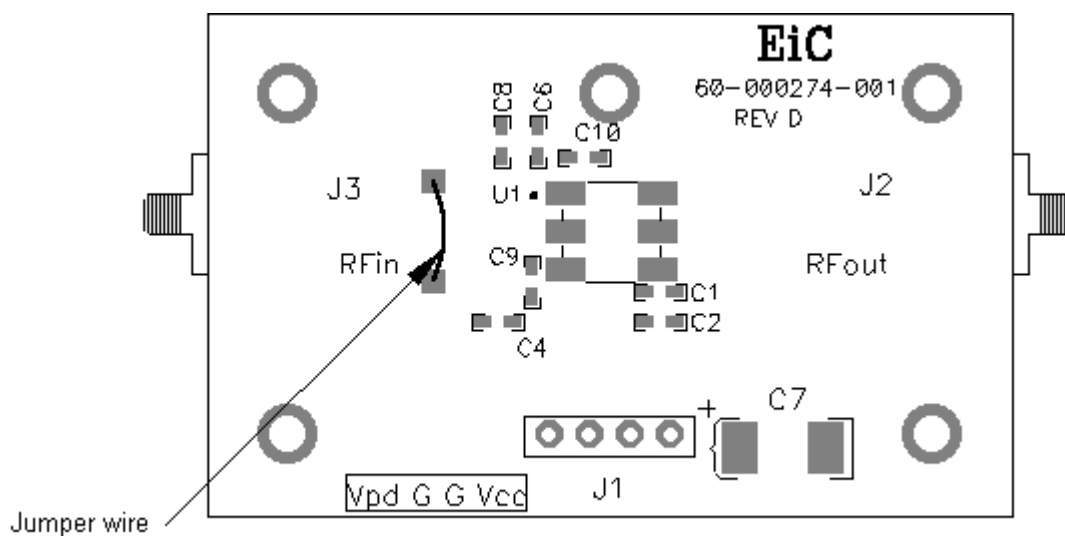




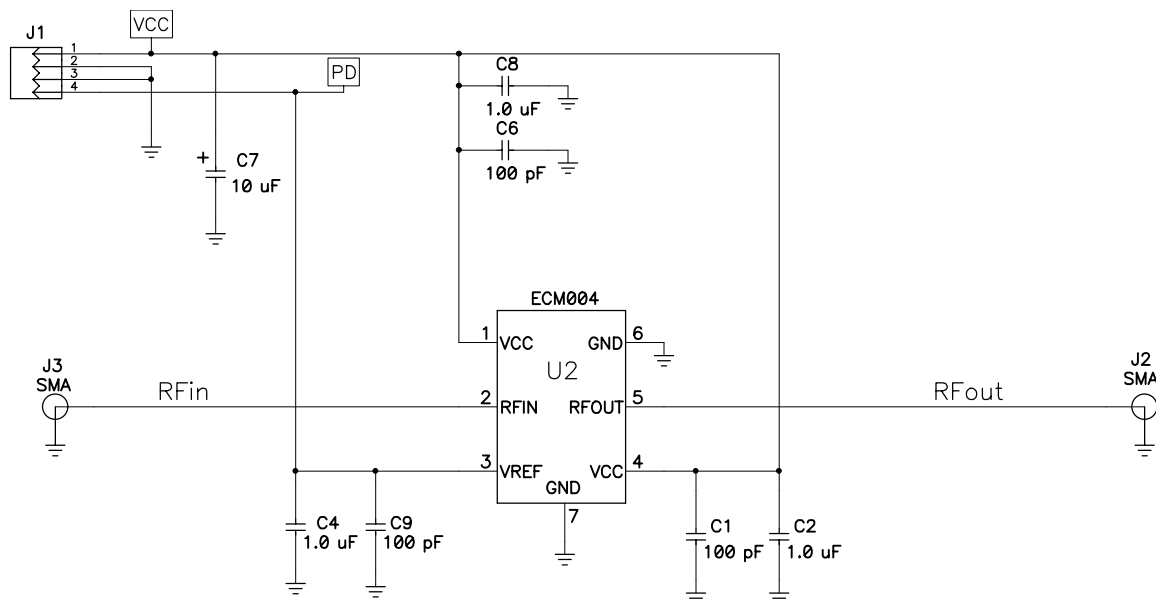
## PCB LAYOUT

1. The front side of the pcb ground area under the PAM requires the use of multiple vias to provide low thermal resistance to the backside of the pcb ground.

## EVAL BOARD



## SCHEMATIC



MANUFACTURER	MFG PART NUMBER	DESCRIPTION	QTY	VALUE	DESIG
ROHM	MCH185A101JK	CAPACITOR, 0603	3	100 pF	C1,9,6
ROHM	MCH182F105ZK	CAPACITOR, 0603	3	1.0 uF	C2,C4,C8
PANASONIC	ECS-HICC106R	CAP 6032 TANT 16V	1	10 uF	C7
SULLINS	PZC04SGAN	CONNECTOR, RT ANG	1	---	J1
CDI	5260CC	CONNECTOR, SMA	2	---	J2,J3
EiC CORPORATION	ECM004	IC, ECM004	1	---	U1
ANY	---	WIRE, 26 AWG	1	---	---
EiC CORPORATION	60-000274-001	PRINTED CIRCUIT BOARD	1	---	---

PIN	FUNCTION	DESCRIPTION
1	Vcc1	PIN 1 connects to the driver stage HBT collector.
2	RF In	RF input port connects to internally matched 50 ohm circuit.
3	Vref / Vpd	Ref. Voltage for the bias circuit. No significant amplifier current is drawn until Vref reaches approximately 2.5V.
4	Vcc2	Vcc2 connects to the power amplifier stage HBT collector.
5	RF Out	RF out is internally matched to 50 ohms and expects a 50 ohm load impedance.
6	GND	Ground
7	GND	Ground. This ground also serves as heat sink and must connect well to the PCB
		RF ground and heat sink.
Notes:		All supply pins may be connected together at the supply.

## ECM004 Operating Principles and Key Features

ECM004 is a 6x6mm size Power Amplifier Module (PAM) for the PCS band CDMA handset market..

The PAM utilizes InGaP HBT technology and a multi layer laminate base, over molded modular package with a LGA signal pad.

### I. In GaP HBT offers Reliability and Quality

EiCs proprietary InGaP HBT provides excellent reliability and is used in the infrastructure industry. The InGaP HBT is inherently superior to AlGaAs HBT. The surface defect density in InGaP is much lower than that of AlGaAs.

The HBT life test of EiC InGaP HBT has gone through 315°C junction temperature and 50kA/cm<sup>2</sup> for over 6000 hours (8 ½ months), translating to multi-million hours lifetime or longer in the operation envelope [1]. This kind of robust performance is far superior to conventional AlGaAs HBT.

The InGaP HBT PAM goes through a product burn-in test as well. A large sample group, usually 100 pieces, goes through burn-in test at an ambient temperature of 125 to 145 °C for 1000 hours. The FIT number is then calculated based upon the data collected. The MTTF is simply 1/FIT, this MTTF should agree with the HBT life test results.

The agreement between the MTTF of HBT from life test and the FIT is essential: it validates both tests! If there is a large discrepancy [2], the quality claim may be flawed.

Although handset applications do not have as stringent operating requirements as the infrastructure market, the high reliability of InGaP HBT offers an assurance to the user of a high quality product designed for high volume production.

### II. InGaP HBT and Patent-pending Circuit Design Offers Low Temperature Variation

Current gain of InGaP HBT varies about 10% over –40 to +85°C range, compared with 50% of AlGaAs HBT. This low gain variation over temperature, coupled with the patent-pending circuit design approach, provides for more stable electrical performance.

### III. ECM004 Offers High Gain and Margin for Transmitter Chain Design

The typical gain of the ECM004 is 27dB. This high gain allows the driver amplifier to run very linear which results in reduced current. Taking into account the 3dB loss of the BPF in front of the PAM, the driver needs to deliver only 4dBm linear power. The P<sub>1dB</sub> of the driver amplifier should be more than 10dBm.

If a lower gain PAM is used, the driver needs to provide more power, at the expense of more operation current and possible degradation in ACPR.

Therefore the ECM004 can replace a lower gain PAM, this allows the driver to work at a lower output power and provide better ACPR, this improved performance offers more design margin in the transmitter chain.

#### IV. Easy Shut Down and Low Leakage Current

The  $V_{cc}$  pin of the PAM is connected directly to the battery, therefore a shut down FET is not required. A voltage is applied to the  $V_{ref}$  pin, which then brings up the quiescent current.

Removing the voltage applied to  $V_{ref}$  pin, the quiescent current will drop to a small leakage current, typically  $<10\mu A$ . The low leakage current of the PAM allows for a longer standby time for the phone.

#### V. General Application

The PAM requires a minimal number of external components. Both the input and output are dc-blocked within the PAM as shown in the function diagram. The input pin is connected to ground through a shunt inductor within the PAM.

ECM004 is designed with a low quiescent current of 80mA typical. At full CDMA power of 28dBm, the operation current will be greater than 500mA. Therefore it is a "quasi class B" or "deep class AB" amplifier. The operation current increases with output power.

CDMA signal has a time varying amplitude. The peak power is 4dB above the average RF power (it can be more accurately defined by PDF, power density function). As the peak power is clipped by the amplifier saturation power level, the distortion of the signal will cause the ACPR to deteriorate rapidly. Therefore the  $P_{1dB}$  (as tested by a SINE wave) of the amplifier should be over 31dBm to provide good ACPR at 28 dBm of output power.

A 100pF capacitor is required adjacent to the  $V_{cc2}$  pin. In addition, a large capacitor ( $>\mu F$ ) is required. The CDMA signal has a time-varying amplitude; therefore the PAM draws on operation current corresponding to the instantaneous demand by the RF power. The large capacitor near-by is the electric charge reservoir, providing current on demand. The long electrical path from battery behaves as a large inductor; the instantaneous demand on current will cause a voltage drop, resulting in poor ACPR.

On the evaluation board, a large shunt capacitor is added to protect the  $V_{ref}$  pin from power supply over-voltage during ON/OFF. This is similar but different from the ESD. Therefore the rise and fall time test of the power down feature needs to be tested with the shunt capacitor on  $V_{ref}$  pin removed.

#### Conclusion

ECM004 offers high gain, low quiescent current, and a small footprint. The InGaP technology provides excellent reliability and quality, assuring the phone set manufacturer a high quality product designed for high volume production.

1. "InGaP HBTs offer Enhanced Reliability", Barry Lin, Applied Microwave and Wireless. pp 115-116, Dec. 2000
2. "Interaction of Degradation Mechanisms in Be-Doped GaAs HBTs", Darrell Hill and John Parsey, Digest GaAs IC Symposium, Oct., 2000. pp 241-244

## APPLICATION NOTES

Please visit our website at [www.eiccorp.com](http://www.eiccorp.com) to view or download the following documents.  
You may also call our Customer Service to request a hardcopy.

Document #	Description
AP-000513-000	Tape and Reel Specifications: PAMS
AP-000516-000	Application Note Index